

**Vishay General Semiconductor** 

# Surface Mount Glass Passivated Ultrafast Rectifier

#### **Major Ratings and Characteristics**

I <sub>F(AV)</sub>	1.0 A
V <sub>RRM</sub>	50 V to 400 V
I <sub>FSM</sub>	30 A
t <sub>rr</sub>	50 ns
V <sub>F</sub>	1.0 V, 1.25 V
T <sub>j</sub> max.	175 °C



Case: DO-213AB, molded epoxy over glass body

Terminals: Matte tin plated leads, solderable per

E3 suffix for commercial grade, HE3 suffix for high

Polarity: Two bands indicate cathode end - 1st band

denotes device type and 2nd band denotes repetitive

Epoxy meets UL-94V-0 Flammability rating

J-STD-002B and JESD22-B102D

peak reverse voltage rating

reliability grade (AEC Q101 qualified)

\*Glass-plastic encapsulation is covered by Patent No. 3,996,602, brazed-lead assembly to Patent No. 3,930,306

**Mechanical Data** 

DO-213AB (GL41)

#### Features

- Cavity-free glass-passivated junction
- Ideal for automated placement
- Ultrafast reverse recovery time
- Low switching losses, high efficiency
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Meets MSL level 1, per J-STD-020C
- Solder Dip 260 °C, 40 seconds

# **Typical Applications**

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and Telecommunication

### **Maximum Ratings**

 $T_A = 25$  °C unless otherwise specified

Parameter	Symbol	BYM12-50	BYM12-100	BYM12-150	BYM12-200	BYM12-300	BYM12-400	Unit
Fast efficient device: 1st band is Green		EGL41A	EGL41B	EGL41C	EGL41D	EGL41F	EGL41G	
Polarity color bands (2nd Band)		Gray	Red	Pink	Orange	Brown	Yellow	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	210	280	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	300	400	V
Maximum average forward rectified current at T_T = 75 $^\circ\text{C}$	I <sub>F(AV)</sub>	1.0						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30						A
Operating junction and storage temperature range	T <sub>J</sub> ,T <sub>STG</sub>	- 65 to + 175						°C

# BYM12-50 thru BYM12-400, EGL41A thru EGL41G

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#### **Electrical Characteristics**

 $T_A = 25$  °C unless otherwise specified

Parameter	Test condition	Symbol	BYM12-50	BYM12-100	BYM12-150	BYM12-200	BYM12-300	BYM12-400	Unit
			EGL41A	EGL41B	EGL41C	EGL41D	EGL41F	EGL41G	
Maximum instantaneous forward voltage <sup>(1)</sup>	at 1.0 A	V <sub>F</sub>	1.0 1.25						V
Maximum DC reverse current at rated DC blocking voltage <sup>(1)</sup>	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	5.0 50						μA
Max. reverse recovery time	at $I_F = 0.5 A$ , $I_R = 1.0 A$ , $I_{rr} = 0.25 A$	t <sub>rr</sub>	50					ns	
Typical junction capacitance	at 4.0 V, 1 MHz	CJ			20		1	4	pF

Notes:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

#### **Thermal Characteristics**

 $T_A = 25$  °C unless otherwise specified

Parameter	Symbol	BYM12-50	BYM12-100	BYM12-150	BYM12-200	BYM12-300	BYM12-400	Unit
		EGL41A	EGL41B	EGL41C	EGL41D	EGL41F	EGL41G	
Maximum thermal resistance <sup>(1, 2)</sup>	$R_{ extsf{ heta}JA}$ $R_{ extsf{ heta}JT}$	60 30						°C/W

Notes:

(1) Thermal resistance from junction to ambient, 0.24 x 0.24" (6.0 x 6.0 mm) copper pads to each terminal

(2) Thermal resistance from junction to terminal, 0.24 x 0.24" (6.0 x 6.0 mm) copper pads to each terminal

#### **Ratings and Characteristics Curves**

(T<sub>A</sub> = 25 °C unless otherwise specified)

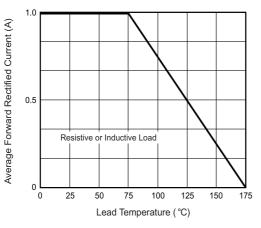


Figure 1. Maximum Forward Current Derating Curve

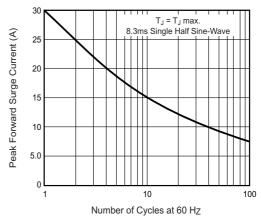


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



1,000

100

10

0.1

0.01

0

Instantaneous Reverse Leakage Current

(MA)

# BYM12-50 thru BYM12-400, EGL41A thru EGL41G

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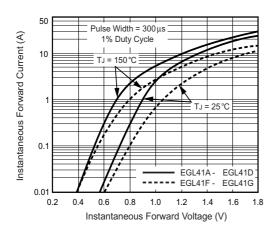


Figure 3. Typical Instantaneous Forward Characteristics

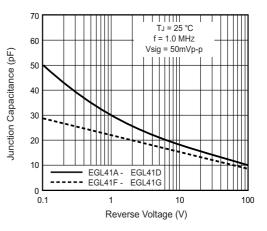


Figure 5. Typical Junction Capacitance

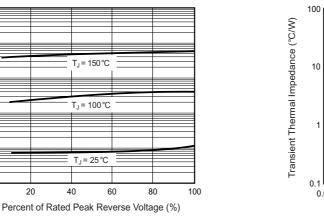


Figure 4. Typical Reverse Leakage Characteristics

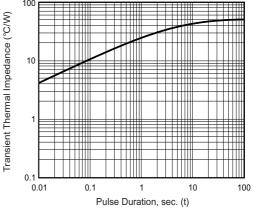
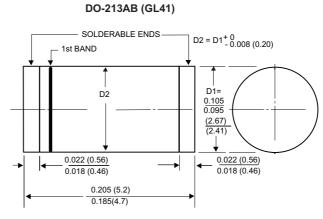


Figure 6. Typical Transient Thermal Impedance

## Package outline dimensions in inches (millimeters)



1st band denotes type and positive end (cathode)



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